







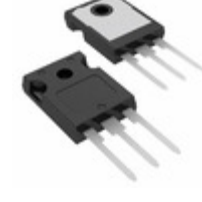
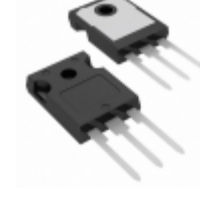
	HGTG12N60A4	
	Hersteller-Teilenummer:	HGTG12N60A4
	Hersteller / Marke:	Fairchild/ON Semiconductor
	Teil der Beschreibung:	IGBT 600V 54A 167W TO247
	Datenblätter:	 HGTG12N60A4.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 10212 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	HGTG12N60A4
Hersteller	Fairchild/ON Semiconductor
Beschreibung	IGBT 600V 54A 167W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	10212 pcs Stock
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	167W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Strom - Kollektor (Ic) (max)	54A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 12A
Strom - Collector Pulsed (Icm)	96A
Schaltenergie	55µJ (on), 50µJ (off)
Gate-Ladung	78nC
Td (ein / aus) bei 25 ° C	17ns/96ns
Testbedingung	390V, 12A, 10 Ohm, 15V
Verpackung	Tube




















HGTG12N60A4 ist neu im Original, Suche HGTG12N60A4 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGTG12N60A4 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage HGTG12N60A4: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>HGTG12N60B3 Fairchild/ON Semiconductor IGBT 600V 27A 104W TO247</p>	 <p>HGTG11N120CND Fairchild/ON Semiconductor IGBT 1200V 43A 298W TO247</p>	 <p>HGTG12N60A4 AMI Semiconductor / ON Semiconductor IGBT 600V 54A 167W TO247</p>	 <p>HGTG12N60A4D AMI Semiconductor / ON Semiconductor IGBT 600V 54A 167W TO247</p>
 <p>HGTG120N60B3D HAR HAR TO-247</p>	 <p>HGTG12N60B3 AMI Semiconductor / ON Semiconductor IGBT 600V 27A 104W TO247</p>	 <p>HGTG11N120CND AMI Semiconductor / ON Semiconductor IGBT 1200V 43A 298W TO247</p>	 <p>HGTG11N120CN Fairchild/ON Semiconductor IGBT 1200V 43A 298W TO247</p>

heiße Teile

Mehr

 GHT1S2N120CN	 HGT1S3N60A4DS	 HGT1S3N60A4DS9A	 D HGT1S3N60A4DS9A	 HGT1S3N60B3DS
 HGT1S3N60C3DS9A	 GHT1S7N60A4DS	 D HGT1S7N60A4DS	 HGT1S7N60A4DS.G7N60A4D	 HGT1S7N60A4DS9A
 GHT1S7N60A4S9A	 HGT1S7N60B3	 GHT1S7N60B3DS	 HGT1S7N60B3S	 HGT1S7N60C3DS9A
 D HGT1S7N60C3DS9A	 HGTD1N120BNS9A	 HGT1S7N60B3DS	 HGTG10N120BND	 HGTG10N120BND
 HGTG11N120CN	 HGTG11N120CN	 GHTG11N120CND	 HGTG11N120CND	 HGTG12N60A4
 HGTG12N60A4D	 HGTG12N60A4D	 D HGTG12N60B3D	 HGTG12N60C3D	 HGTG12N60C3D
 GHTG18N120BN	 D HGTG18N120BN	 HGTG18N120BND	 HGTG18N120BND	 HGTG20N120CND
 HGTG20N120E2	 GHTG20N50C1D	 HGTG20N60	 HGTG20N60A4	 HGTG20N60A4
 GHTG20N60A4D	 HGTG20N60A4D	 GHTG20N60B3	 D HGTG20N60B3	 HGTG20N60B3D
 HGTG20N60B3D	 GHTG20N60C3	 HGTG20N60C3D	 GHTG20N60C3D	 HGTG24N60D1

Contact us: Info@Y-IC.com

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